

# Schottky Barrier Rectifier

# MS1004

<ul> <li>Low Fo</li> <li>High Op</li> <li>Low Po</li> <li>High su</li> <li>Minimute</li> </ul>	ES Ring for Stress Protection rward Voltage perating Junction Temperature wer Loss/High Efficiency rge capability m Lot-to-Lot variations for robust dev nance and reliable operation	vice		2 1 3 PIN 1.2:Cathor 3:Anode TO-220C3 package
• Case: E	ICAL CHARACTERISTICS Epoxy, Molded E MAXIMUM RATINGS(Ta=25°C)			
SYMBOL	PARAMETER	VALUE	UNIT	
Vrrm Vrwm Vr	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	40	V	¢ mm
I <sub>F(AV)</sub>	Average Rectified Forward Current ) $T_C$ = 125 $^\circ\!C$	10	A	DIM MIN MAX A 15.50 15.90 B 9.80 10.20
IFSM	Nonrepetitive Peak Surge Current (Surge applied at rated load conditions half-wave, single phase, 60Hz)	225	A	B         9.80         10.20           C         4.20         4.50           D         0.70         0.90           F         3.40         3.70           G         4.98         5.18
TJ	Junction Temperature	-55~175	°C	H <b>2.6</b> 8 2.90 J 0.44 0.60
T <sub>stg</sub>	Storage Temperature Range	-55~175	°C	K         12.80         13.40           L         1.20         1.45           Q         2.70         2.90           R         2.30         2.70
dv/dt	Voltage Rate of Change (Rated $V_R$ )	10,000	V/ µ s	S         1.29         1.35           U         6.45         6.65           V         8.66         8.86



### **Schottky Barrier Rectifier**

### INCHANGE SEMICONDUCTOR

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### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.5	°C <b>/W</b>

#### ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 µ s,Duty Cycle≤2%)

	SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
_	VF	Maximum Instantaneous Forward Voltage	I <sub>F</sub> = 10A ; T <sub>C</sub> = 25℃ I <sub>F</sub> = 10A ; T <sub>C</sub> = 175℃	0.65 0.48	V
	I <sub>R</sub>	Maximum Instantaneous Reverse Current	Rated DC Voltage, T <sub>C</sub> = 25 $^\circ$ C Rated DC Voltage, T <sub>C</sub> = 125 $^\circ$ C	0.25 10	mA

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